# Understanding and Characterizing Side Channels Exploiting Phase Change Memories

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Abstract—Recent advances in non-volatile memory (NVM), together with their performance-optimized architectural schemes, position NVMs as promising building blocks for future main memory. However, the security of such techniques has not been explored. This article performs the first study on information leakage threats in phase change memories (PCM). We propose an attack framework, R-SAW, that systematically investigates side channel vulnerabilities in representative read techniques under inter-line and intra-line interleaving for multi-level cells. Our evaluation shows that the new side channels can accurately leak program secrets (e.g., crypto keys) and are extremely robust to noise. Our work highlights the need to understand microarchitecture security for emerging memory devices.

### 1. Introduction

Recent developments in microarchitecture attacks have raised significant concerns for information security. Particularly, a burgeoning of side channels has been demonstrated in a plethora of processor hardware components [1], [2]. These exploitations highlight the fact that hardware performance optimizations without proper consideration of security often open new venues for information leakage. As new hardware components and microarchitecture optimizations are more rapidly integrated into modern computing systems, understanding their security impacts is critical to ensure secure-by-design solutions.

Emerging memory technologies have become major contenders for main memory with their advantage in non-volatility, outstanding capacity, and superior energy efficiency [3]. Phase chase memory (PCM) is a promising class of nonvolatile memories (NVMs) due to its maturity and DRAM-comparable performance [4]. To enable the efficient integration of PCM in computing systems, many architectural schemes for optimizing PCM main memory have been proposed in recent years [4], [5], [6]. While tremendous efforts have been put into studying the microarchitecture security of on-chip resources, information leakage vulnerability in architectural schemes for PCM has not been well understood.

This article demonstrates the first work on investigating side channels in future systems equipped with phase change memory. We systematically surveyed state-of-the-art read techniques for PCM operating under the multi-level cell (MLC) mode, a widely-utilized configuration that increases memory capacity. We identify that mainstream architectural schemes for PCM read commonly leverage the read asymmetry in MLC cells for performance optimization, which allows highly variable program executions due to access to fast/slow data regions. Accordingly, we propose a novel side channel framework-R-SAW-that aims to exfiltrate program secrets by correlating victims' execution times with the PCM access patterns. We present two variants of side channel attacks: 1) R-SAW-I that targets memory read technique with PCM inter-line data striping, and 2) R-SAW-IA exploiting PCM accesses under intra-line data striping. Our evaluation demonstrates that the newly discovered side channels are particularly dangerous: First, such attack can observe timing variance for victim's execution even under the same execution path (e.g., inferring AES keys); Second, R-SAW is able to carry out information leakage based on the *sub-cache line* access granularity, making existing mitigations against cache line level exploits ineffective. Our work provides novel insights for future research in securing emerging NVM-based systems against side channels. In contrast to our previous work [7], the major contributions of this article are:

- We systematically model the architectural read technique under PCM intra-line interleaving scheme and identify a new R-SAW side channel (R-SAW-IA) exploiting timing variations due to sub-memory block access in PCM.
- We present possible code patterns that are resistant to side channels observing at the memory block granularity while still exploitable via R-SAW-IA. We evaluate the attack with the prototyped victim (based on RSA) and show that R-SAW-IA can accurately unveil secretive data from the victim.
- We perform additional characterizations for both R-SAW-I and R-SAW-IA and show that not only the proposed side channels are independent of other on-chip structures that contributes to timing observation (i.e., caches), but they are also more robust to noises. We further extend the discussion on the security of PCM with side channels.

## 2. Background and Related Works

### 2.1. Phase Change Memories

PCM devices are built with phase-change materials that can switch between high resistance amorphous state and low resistance crystalline state. Due to the fact that the programmable resistance range is considerably large, it is possible to store multiple bits by encoding more than two resistance levels in a single PCM cell (i.e., multi-level cell or MLC), which significantly increases the device capacity (shown in Figure 1). Accessing PCM in MLC mode, however, brings additional complexity to the cell sensing operation. Particularly, the state-of-the-art MLC sensing technique (for reads) leverages an iterative process where the resistance in one cell is compared to multiple reference values (one at a time) to decode each individual bit from the order of MSB (Most Significant Bit) to LSB (Least



Figure 1: MLC PCM cell resistance range (Left) and the MLC read technique (Right).



Figure 2: Memory block bits layout with PCM: (a) default bit organization in a cache line (CL); (b) inter-line striping with MSB-only CL ( $CL^h$ ) and LSB-only CL ( $CL^l$ ); and (c) intra-line striping with *partial* cache line (i.e., first half) in MSBs ( $pCL^h$ ) and the other half in LSBs ( $pCL^l$ ).

Significant Bit) (Figure 1).

With iterative sensing, it generally takes longer to derive the lower bits in an MLC cell than the higher ones-read asymmetry. For instance, in 2-bit MLCs, reading from LSBs is about  $2 \times$  slower than that from MSB. As memory load is in the critical path, it is desirable to enable the *decoupling* of the MSB accesses with shorter latencies from the LSB accesses with longer latencies. Towards this end, the architecture community has proposed several data striping schemes and necessary architecture support to utilize the PCM read asymmetry for performance optimizations [6], [5]. Figure 2 illustrates the representative data interleaving designs including 1) bit-interleaving where consecutive cache line bits are mapped to MLC cell bits sequentially (nonoptimized scheme), 2) inter-line interleaving with consecutive odd and even lines stored in MSB bits and LSB bits (speeding up odd line accesses), respectively ([5]). 3) intra-line interleaving in which one-half of the line maps to MSBs and the other half to LSBs (speeding up access of half of a memory block) [6].

## 2.2. Microarchitecture Side Channels

Microarchitecture side channel is a form of information leakage attack where illicit communication is built by an adversary through modulating microarchitecture states that influence the *timings* of instruction executions (i.e., latency) either observed through an attacker or the victim process. A variety of on-chip hardware components have been shown to be vulnerable to side channel exploitation [2], [8], [9]. Timing channels can be categorized into two classes: 1) active timing channel where an adversary intrusively perturbs states of hardware components (e.g., evicting victim's cache line), and 2) passive timing channel where the attacker only needs to passively observe the execution times of the victim process. While existing protection mechanisms (i.e., randomized cache [1] and resource partitioning) can defeat many of these attacks, new avenues of exploitation open up [7].

### Threat Model and Assumptions

We assume a victim is running processes on machines equipped with PCM as the main memory. Architectural optimizations are integrated to enhance PCM memory performance by supporting various data-interleaving schemes. The adversary can either co-run a *userspace* process or interact with the victim's process through software interfaces (e.g., serving client's requests). Our investigation focuses on passive timing channels where the attacker monitors externally-observable execution time of the victim and attempts to infer the secretive information. To analyze the vulnerabilities, we model a system with PCM main memories with key architecture parameters in the gem5 simulator as shown in Table 1.

## 4. Side Channels in Inter-line Striped Phase Change Memories

## 4.1. Architecture Support for PCM with Inter-line Interleaving

We thoroughly model PCM-based systems that integrate the state-of-the-art inter-line striping bit arrangements in MLC PCM [5]. In this scheme, the memory controller maps consecutive memory blocks in MSBs  $(CL^h)$  and LSBs

Hardware	Configurations
Processor	Quad-core x86 CPU, Out-of-order execution
L1 I/D-Cache	Private, 32KB, 2-way, 1-cycle hit
L2 Cache	Private, 4MB, 16-way, 10-cycle hit
DRAM Cache	Shared, 32MB, 16-way, 50-cycle hit
Mem. Ctrl.	64 RD & WT queue, FR-FCFS, open-row
PCM Memory	8GB, single channel, 2 ranks/channel (Local) 16GB, dual channel, 2 ranks/channel (Target)
PCM Timing	2-bit MLC, MSB read: 28ns, LSB read: 48ns

Table 1: Architecture configurations.

 $(CL^l)$  alternatively. Hence, in one pair of memory blocks, the first block is mapped entirely in the MSB and the second block is mapped to LSB of the same group of PCM cells. Using this bit organization, the  $CL^h$  reads are serviced quickly by the memory controller. Additionally, when servicing reads to  $CL^l$  blocks, the controller searches for the paired  $CL^h$  block in cache, and if hit, the  $CL^l$  read is performed in one iteration of sensing as well.

## 4.2. Case Study: Attacking AES

We first demonstrate R-SAW-I, an attack that can recover keys from AES cryptographic system by exploiting inter-line read latency variations. Specifically, OpenSSL's implementation of AES-128 performs ten rounds of transformation using five T-tables ( $T_{0-4}$ ). The specific entry accessed in tables depends on the corresponding round key byte and the intermediate input byte.

As the total number of T-table accesses in AES is fixed during each encryption run, a direct correlation between  $CL^l$  access ratio and encryption latency may exist. Since T-table access addresses are reliant on the round key, we conjecture that when performing encryptions, *each particular value of key bytes will result in deterministic PCM access patterns*. Based on this conjecture, an attacker can extract the exact value of key bytes by performing correlation analysis with encryption latencies for all possible 256 values of the key byte. R-SAW-I comprises the following steps:

**PCM Access Pattern Profiling on AES.** During this stage, the attacker compiles *memory-pattern vectors* (MPVs) which are later used to determine specific key bytes in victim. The attacker first instruments the AES program to detect  $CL^h$  and  $CL^l$  line accesses during encryption. Then it performs a sufficient number of encryptions on



Figure 3: A complete recovery of the final round key. Each row denotes the correlation value distribution for one key byte.

a local machine, using random keys and plaintexts, to generate PCM access traces. For each encryption run, a sample point  $S = (C, K^{10}, p)$  is collected, recording the corresponding ciphertext C, last round key  $K^{10}$  and the percentage of  $CL^{l}$  access p. These samples are then categorized based on every unique combination of  $k_i^{10}$  and  $C_i$  for each *i*. Particularly, we arrange all sample points with  $K_i^{10} = u$  and  $C_i = w$  (u and  $w \in [0, 255]$ ) as a group  $\mathcal{S}(i, u, w)$  for each value of  $i^{th}$  key byte. This  $\mathcal{S}(i, u, w)$  encodes the statistical PCM access pattern for specific values of  $i^{th}$  key byte and ciphertext byte. Finally, we calculate the  $\overline{P}_{(i,u)}^{w}$  by taking average of  $CL^{l}$ access percentage in  $\mathcal{S}(i, u, w)$ . The MPV for  $i^{th}$ byte is subsequently defined as:

$$\mathcal{M}(i,u) = \{ \overline{P}_{(i,u)}^{0}, \overline{P}_{(i,u)}^{1}, ..., \overline{P}_{(i,u)}^{255} \}$$
(1)

Victim's Execution Time Monitoring. The attacker triggers AES encryption on victim system using random plaintexts and records S = (C, l), where C is the ciphertext, and l is the execution latency. Similar to the profile step, the collected samples are organized such that for each  $i^{th}$ ciphertext byte, the S records for the same  $C_i$ are grouped as  $S(i, \mathbf{x}, w)$ , here  $\mathbf{x} = K_i^{10}$  is the unknown key (fixed). Subsequently, the attacker builds an *encryption-timing vector* (ETV) for each byte of last round key by calculating  $\overline{L}_{(i,\mathbf{x})}^w$ based on *average latency* for each  $S(i, \mathbf{x}, w)$ . The ETV captures the statistical encryption latency pattern for the unknown value of  $i^{th}$  key byte, and is denoted as:

$$\mathcal{T}(i,\mathbf{x}) = \{\overline{L}_{(i,\mathbf{x})}^0, \overline{L}_{(i,\mathbf{x})}^1, ..., \overline{L}_{(i,\mathbf{x})}^{255}\}$$
(2)

AES Key Recovery through Correlation Analysis. After the ETV collection  $(\mathcal{T}(i, \mathbf{x}))$  is completed, the attacker performs correlation analysis of ETV with MPVs to infer the secret key value. We expect that an outstandingly higher correlation between  $\mathcal{M}(i, u)$  and  $\mathcal{T}(i, \mathbf{x})$  will exist for  $\mathbf{x} = u$ . We represent this procedure as:

$$K_i^{10} = \arg\max_u R(\mathcal{M}(i, u), \mathcal{T}(i, \mathbf{x}))$$
(3)

Based on this, each last round key byte can be inferred by finding the u that results in the highest correlation with x for that specific byte. Once all bytes of last round key are inferred, the original key can be recovered [8].

#### 4.3. Evaluation

We first generate MPVs using 30M encryptions in local system. Additionally, we perform 128K encryptions in the victim to generate the ETV. From our profiling result, we observe that MPV for each key byte ( $\mathcal{M}(i, u)$ ) corresponding to different values is differentiable. Figure 3 shows the correlation analysis of ETVs for each of the 16 key bytes. We observe that for each key byte, there exists an obvious outlier representing strong and highest correlation, which is the correct key byte value. We run this for 4000 different victim key settings and observe R-SAW-I achieves 98.5% accuracy.

## 5. Side Channels in Intra-line Striped Phase Change Memories

## 5.1. Architecture Support for PCM with Intra-line Interleaving

We model PCM intra-line optimization as proposed in [6]. Specifically, bits in each memory block are organized in such a way that the first half of the block ( $pCL^h$  in Figure 2c) is stored in only the MSB of PCM cells, and the second half ( $pCL^l$ ) in the LSB of the same PCM cells. When the processor loads a memory block from main memory, the  $pCL^h$  read finishes faster and



Figure 4: Intra-line access for secret-dependent control flow (Left) and data flow (Right).

can be ready before the  $pCL^{l}$  (See Section 2). To optimize performance, the memory controller utilizes *early forwarding* of  $pCL^{h}$  to the requesting core while only marking the outstanding cache miss as completed when  $pCL^{l}$  arrives. This optimization improves program execution time by opportunistically hiding the LSB read latency.

### 5.2. Potential Side Channel Vulnerabilities

Since intra-line optimization can forward  $pCL^h$  earlier than  $pCL^l$ , executions requiring  $pCL^h$  can progress while waiting for  $pCL^l$ . At runtime, software can issue memory access that either only maps to  $pCL^{h}$  or  $pCL^{l}$  of a memory block, leading to variable timings. To understand the potential impact of intra-line access pattern, we design a microbenchmark that reads from arbitrary halves of memory blocks. By controlling  $pCL^h$  access ratio, we observe program execution time increases linearly with  $pCL^{l}$ . We also observe that this timing correlation only exists with the presence of the intra-line striping optimization. We illustrate two representative program patterns that are potentially exploitable as shown in Figure 4.

• Sub-cache line control flow divergence: In this pattern, a secret dependent branch (inside a  $pCL^{l}$ ) can transfer the control flow to either the  $pCL^h$  or  $pCL^l$  in the next memory block (Figure 4a). In such cases, the taken path may skip  $pCL^h$  and diverge the control flow to  $pCL^{l}$ , whereas the nottaken path will execute through  $pCL^h$ . Since the taken path needs to execute instructions belonging to  $pCL^{l}$  on first access, this exposes intra-cache line level latency variations in program execution time. The PCM read latency variations observed in this case are typically much higher than the execution time differences due to the difference between these two paths in terms of instructions.

• Sub-cache line data flow transfer: In this vulnerable code, secret-dependent memory access can index to either a  $pCL^h$  or  $pCL^l$  of the same memory block (Figure 4b). Based on the execution latency, it is possible to determine which half line is indexed into, thus revealing the secret value.

counter.

Snippet 2: Square-andmultiply-always.

Since the timing variance corresponds to different accesses within a memory block, such vulnerability can manifest in cases where programs do not exhibit differentiable activities at cache line granularity (e.g., classical cache attacks exploiting hit/miss [2]). Code Snippets 1 and 2 (explained later) demonstrate two representative code gadgets corresponding to the vulnerabilities in Figure 4. Specifically, Code Snippet 1 illustrates a secret-dependent data access to different halves of memory block. As shown in the gadget, if both variables highCtr and lowCtr belong to the same cache line, this gadget does not have any cache line level vulnerability. However, intra-cache line level vulnerability still exists in case these two data access map to a  $pCL^h$ and  $pCL^h$ , respectively. Note that such gadgets are common in image processing applications (e.g., Libjpeg), where transformation of images (memory accesses) often depends on the values of neighboring pixel values.

### 5.3. Case Study

We present R-SAW-IA, a side channel utilizing intra-cache line level access pattern. At a high level, R-SAW-IA profiles the execution latency of the target application for each possible secret value (i.e., offline profiling stage). Once profiling is completed, the attacker triggers victim execution and records the execution times. Finally, a correlation analysis between the victim execution time with the attacker's profile data leaks the



Figure 5: Total program execution latency as a function of # of bits '1's in the exponent for Code Snippet 2.

secretive information. To demonstrate R-SAW-IA, we analyze the modular exponentiation algorithm using square-and-multiply-always [10] for GnuPG's RSA implementation as shown in Code Snippet 2. Specifically, it performs multiplication regardless of the value of the current exponent bit and the result of multiplication operation is only kept if the exponent bit is '1'. The implementation was proposed to defeat cache timing channels that identify cache line access due to the invocation of the multiplication operations in the original RSA algorithm [2]. Importantly, although there is a branch (Line 8) that depends on the secret bit, the branch block is typically very small and can be placed within the same cache line as the non-secret dependent instructions before it (i.e., line 7 and above). However, the secret dependent code can still spawn over half of cache line (i.e., LSB half) similar to the case in Figure 4a. In this case, although such control flow path cannot be observed from caches (as the same cache lines would be accessed in either direction), the sub-memory block level observation in intra-line optimization remains. The exploitation steps are:

**Profiling of Execution Latency.** In this step, attacker runs RSA encryptions with different values of e, and collects the execution latency for each. The attacker then creates an execution latency profile corresponding to each number of bit '1's in the exponent (i.e.,  $n_e$ ). After this stage, the attacker has an *execution latency vector* (ELV) that captures the execution time signature of the victim process corresponding to each  $n_e$  in e.

Collecting Victim Latency Traces. In this step,



Figure 6: Comparative study of R-SAW-I and cache-based attack.

the attacker triggers victim execution which runs RSA encryption with an unknown e. Attacker measures the execution latency corresponding to this unknown exponent.

**RSA Exponent Secret Recovery using Correla**tion Analysis. The attacker performs correlation analysis of the victim latency traces against the profiled ELV. Since the  $n_e$  is representative of additional  $pCL^l$  access during RSA encryption, the victim program execution time is a function of the unknown  $n_e$ . For the guessed  $n_e$  whose ELV results in the highest correlation with victim traces is determined to be the number of bits '1's in victim's exponent.

#### 5.4. Evaluation

We evaluate R-SAW-IA by launching the attack based on Code Snippet 2. Note that as the attacker observes the entire program execution time of the victim, the timing observation collectively includes all the iterations in the loop. Figure 5a shows that indeed program execution time increases linearly with the increase of the  $n_e$  value. In contrast, when intra-line striping optimization is not enabled, such correlation does not exist (as illustrated in Figure 5b). We collect victim encryption latency traces for 1000 different values of exponent *e*. R-SAW-IA can determine the  $n_e$  in each of them with 93% accuracy.

## 6. Characterizing Robustness of PCM Side Channels

## 6.1. Characterization of R-SAW-I

Sensitivity to Sample Size: We evaluate the Success Rate (SR) by changing the number of samples taken from victim execution. Figure 6a illus-

trates that by increasing the number of samples per key from 25K to 140K, both R-SAW-I and cache-based attacks have improvements over SR. However, we observe that given a fixed sample size, R-SAW-I consistently attains higher SRcompared to the cache-based attack.

Resiliency to System Noise: Along with the victim encryption process, we run a multi-threaded noise injection process that continuously accesses main memory. By varying the frequency of memory accesses, we can control the noise level. We run both attacks under each noise level and compute SR for 100 AES keys (with 128Ksample points each). Figure 6b shows that SRfor cache-based attack reduces drastically with the increase in noise level. Particularly, there is a sharp decrease of SR when the noise level is higher than 40%. In contrast, R-SAW-I can maintain 81% accuracy under the highest noise (i.e., non-stop memory reads). This is because while cache-based attack relies on cache hit activities (i.e., if both the  $i^{th}$  and  $j^{th}$  key bytes use the same  $T_4$  entry, the encryption latency is lower because of cache hit), and cache can be heavily polluted becuase of the additional memory reads due to noise. In contrast, R-SAW-I relies on PCM access pattern (i.e., percentage of  $CL^{l}$  reads) that remains unaffected by the additional memory accesses.

Impact of On-chip Caching: We model systems that either: a) do not cache memory accesses, thus only keeping PCM access-based leakage; or b) do not integrate PCM line striping, thus only keeping cache-based leakage. In Figure 6a, the error bar on *R-SAW-I attack* represents R-SAW-I *SR* due to PCM memory access pattern only (which is only 1%-4% lower than default), and the error bar on *Cache attack* represents the *SR* due to cache activity only (which is 2%-9% lower than default). As expected, R-SAW-I attack is possible due to secret-dependent PCM access pattern, and it is not influenced by caches.

#### 6.2. Characterization of R-SAW-IA

We characterize R-SAW-IA by evaluating it with the chosen-plaintext attack on RSA, leaking the number of bits '1's in the secret exponent. We choose 100 plaintexts and generate the profile ELVs from 30M encryptions, as discussed in Sec-



(a) Correlation between *ELV* and victim(b) Success rates vs sysencryption latency trace. tem noise

Figure 7: R-SAW-IA attack analysis.

tion 5.3. Then, we collect 1000 victim encryption latency traces for each of the 100 plaintexts. Finally, we run correlation analysis of the victim trace against the ELVs. For example, Figure 7a illustrates that the correlation value is the highest when  $n_e$  is 1950, which represents the correct  $n_e$ in victim. This highlights the strong correlation between  $n_e$  and overall encryption latency that is directly caused by intra-line optimization of PCM reads.

Impact of System Noise: Similar to the R-SAW-I, we define 6 levels of system noises along with the noise-free configuration to quantify the noise resiliency of R-SAW-IA. Figure 7b shows that even with the highest degree of noise, R-SAW-IA observes a reasonable 78% top-3 accuracy (i.e., the correct  $n_e$  is in one of the top 3 correlations). As the  $pCL^h$  to  $pCL^l$  access ratio remains unaffected by the additional memory accesses, R-SAW-IA is less susceptible to noise. We note that with intra-line interleaving, regardless of which half of the memory block is accessed, both  $pCL^{h}$ and  $pCL^{l}$  reads are performed in memory to return the complete memory block to the processor. Hence, the performance benefits of intra-line interleaving mainly come from early execution of instructions utilizing  $pCL^{h}$ . In contrast, with inter-line interleaving, memory reads can be terminated early if  $CL^h$  is read, which results in both early execution of instructions and higher memory throughput for applications with  $CL^h$ reads. This results in R-SAW-I observing higher degree of read latency variations compared to R-SAW-IA. Nevertheless, R-SAW-IA is still capable of exploiting the intra-line latency variations with high noise resiliency.

## 7. Discussions of Mitigation

Randomized PCM Data Mapping. One potential way to mitigate the attack is to randomize memory block mapping to MSBs and LSBs using architectural support in memory controller. For inter-line striping, MSBs and LSBs can be remapped to new locations on the same page using a permutation seed generated at runtime. For intra-line striping, instead of mapping first half of a block to MSB and second half to LSB, they can be remapped to different halves in the same block randomly. This will make the memory-access pattern randomized, breaking the correlation with execution latency. However, this scheme might require frequent changes of the randomization seed to prevent potential reverseengineering of the mapping.

**Software Hardening.** Software optimization is also be one potential mitigation. Prior research has investigated rewriting the software to ensure information safety (e.g., preventing secret dependent branching), which can be adopted to prevent R-SAW. Specifically, security-critical sections in applications can be allocated to memory locations with similar latency groups to prevent secretdependent PCM access latency. However, adapting such PCM latency region-aware mapping techniques in software can introduce non-trivial complexity in software design.

### 8. Conclusion

In this paper, we investigate the information leakage vulnerabilities in MLC PCM systems. We find that PCM access techniques leveraging read asymmetry in multi-level cells introduce new side channel attacks. We present two variants of attack, targeting both inter-line and intra-line interleaving optimizations. Our work highlights the importance of understanding security in systems integrated with emerging memory technologies and motivates the need to architect secure-bydesign PCM main memories in the future.

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